

ID	$R_{DS(ON)}$ (Typ)	VDSS
7A	1.0Ω	500V

Applications:

- Motor control
- Uninterruptible Power Supplies
- Zero Voltage Switching Smps

Features:

- Fast body Diode
- Low on-Resistance
- Fast switching
- High input Resistance
- ROHS compliant

Ordering Information

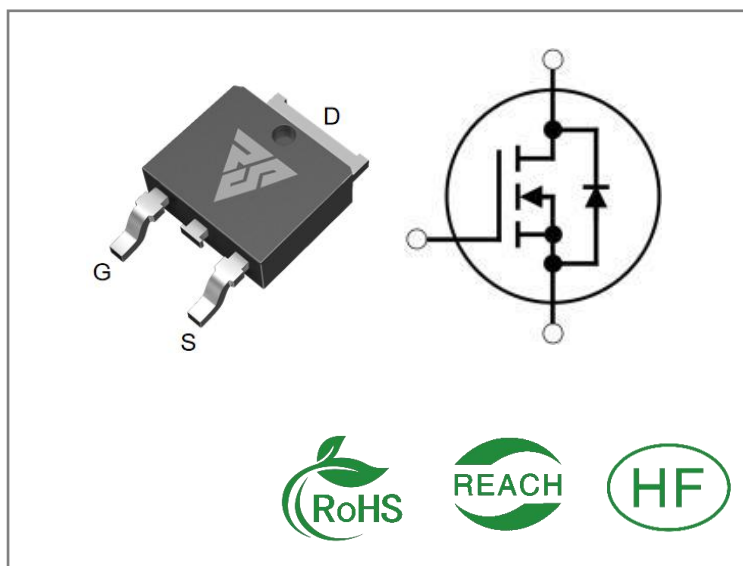
Part Number	Package	Marking	Packing	Qty.
RSF7N50CD	T0-252	RSF7N50CD	Tape&reel	2500 PCS

Absolute Maximum Ratings $T_c = 25^\circ\text{C}$ unless otherwise specified

Symbol	Parameter	RSF7N50CD	Units
VDSS	Drain-to-Source Voltage	500	V
ID	Continuous Drain Current $T_C=25^\circ\text{C}$ Continuous Drain Current $T_C=100^\circ\text{C}$	7 3.9	A
IDM	Pulsed Drain Current (Note*1)	24	
PD	Power Dissipation	119	W
VGS	Gate- to- Source Voltage	± 30	V
EAS	Single Pulse Avalanche Energy $L=20\text{mH}$, $V_{DD} = 50\text{V}$, $R_G = 25\ \Omega$, $I_{AS}=6.0\text{A}$, $T_C=25^\circ\text{C}$	360	mJ
TL TPKG	Maximum Temperature for Soldering	300	$^\circ\text{C}$
	Leads at 0.063in(1.6mm)from Case for 10 seconds Package Body for 10 seconds	260	
TJ and TSTG	Operating Junction and Storage Temperature Range	-55 to 150	

* Drain Current Limited by Maximum Junction Temperature

Caution: Stresses greater than those listed in the "Absolute Maximum Ratings" Table may cause permanent damage to the device.



Thermal Resistance

Symbol	Parameter	RSF7N50CD	Units	Test Conditions
R θ JC	Junction-to-Case	1.05	$^{\circ}\text{C} / \text{W}$	Drain lead soldered to water cooled heatsink, PD adjusted for a peak junction temperature of + 1 5 0 $^{\circ}\text{C}$
R θ JA	Junction-to- Ambient	110		1 cubic foot chamber,free air.

OFF Characteristics TJ= 25 $^{\circ}\text{C}$ unless otherwise specified

Symbol	Parameter	Min.	Typ.	Max.	Units	Test Conditions
BVDSS	Drain- to- source Breakdown Voltage	500	--	--	V	VGS=0V,ID=250 μA
IDSS	Drain- to- Source Leakage Current	--	--	1	μA	VDS=500V VGS=0V
IGSS	Gate- to- Source Forward Leakage	--	--	100	nA	VGS=30V , VDS=0V
	Gate- to- Source Reverse Leakage	--	--	-100		VGS=30V , VDS=0V

ON Characteristics TJ=25 $^{\circ}\text{C}$ unless otherwise specified

Symbol	Parameter	Min.	Typ.	Max.	Units	Test Conditions
RDS(on)	Static Drain- to- Source On-Resistance(Note*2)	--	1.0	1.3	Ω	VGS=10V,ID=3.0A
VGS(TH)	Gate Threshold Voltage	3	--	5	V	VGS=VDS ID=250 μA

Resistive Switching Characteristics Essentially independent of operating temperature

Symbol	Parameter	Min.	Typ.	Max.	Units	Test Conditions
td(ON)	Turn- on Delay Time	--	23	--	nS	VDS=250V ID=6A RG=27 Ω
trise	Rise Time	--	47	--		
td(OFF)	Turn- OFF Delay Time	--	53	--		
tfall	Fall Time	--	25	--		

Dynamic Characteristics Essentially independent of operating temperature

Symbol	Parameter	Min.	Typ.	Max.	Units	Test Conditions
Ciss	Input Capacitance	--	534	--	pF	VGS=0V VDS=25V f=1.0MHz
Coss	Output Capacitance	--	68	--		
Crss	Reverse Transfer Capacitance	--	11	--		
Qg	Total Gate Charge	--	14	--	nC	VDS=50V ID=6A VGS=10V
Qgs	Gate- to- Source Charge	--	3.9	--		
Qgd	Gate-to-Drain(" Miller") Charge	--	7.1	--		

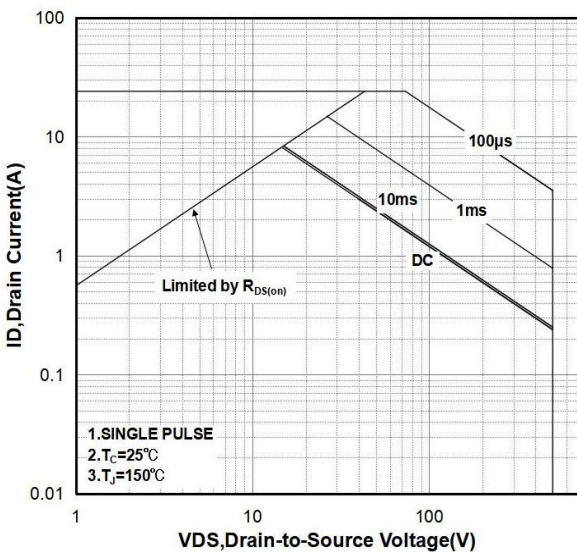
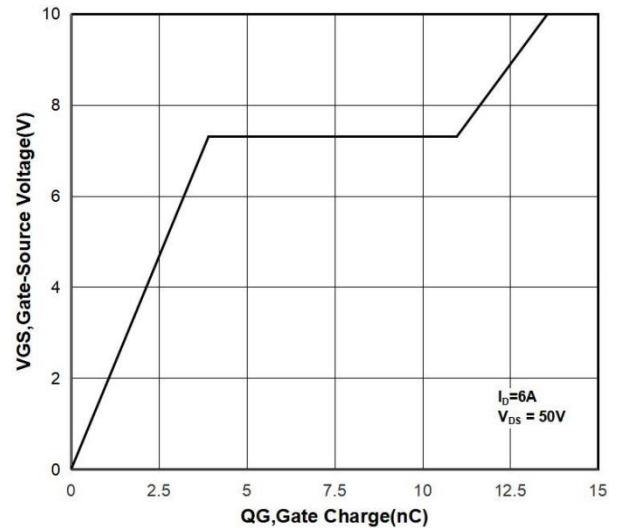
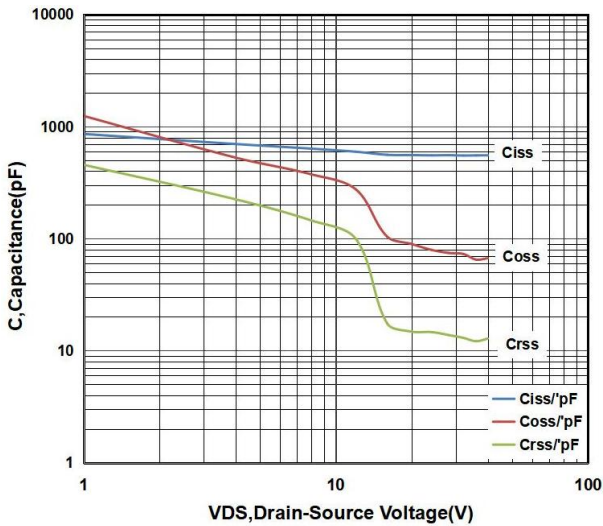
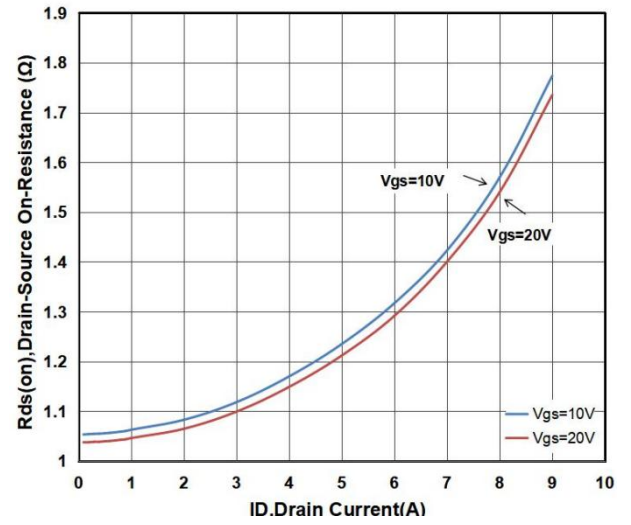
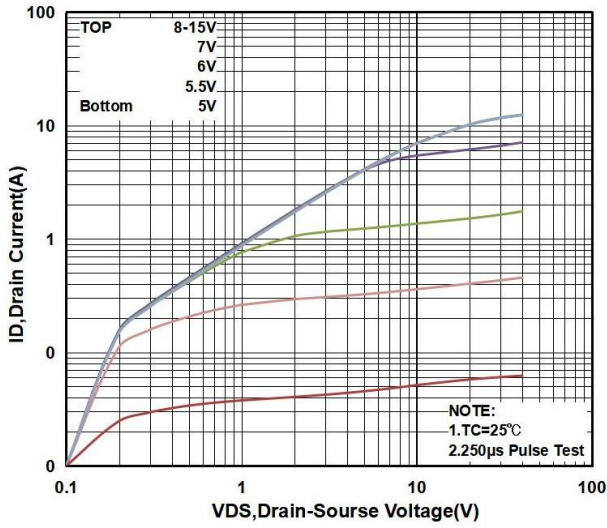
Source- Drain Diode Characteristics

Symbol	Parameter	Min.	Typ.	Max.	Units	Test Conditions
IS	Continuous Source Current	--	--	7	A	Integral pn- diode in MOSFET
ISM	Maximum Pulsed Current	--	--	24	A	
VSD	Diode Forward Voltage	--	--	1.4	V	IS=6A,VGS=0V
trr	Reverse Recovery Time	--	135	--	nS	Tj=25℃ IF=6A di/dt=100A/μs
Qrr	Reverse Recovery Charge	--	364	--	nC	

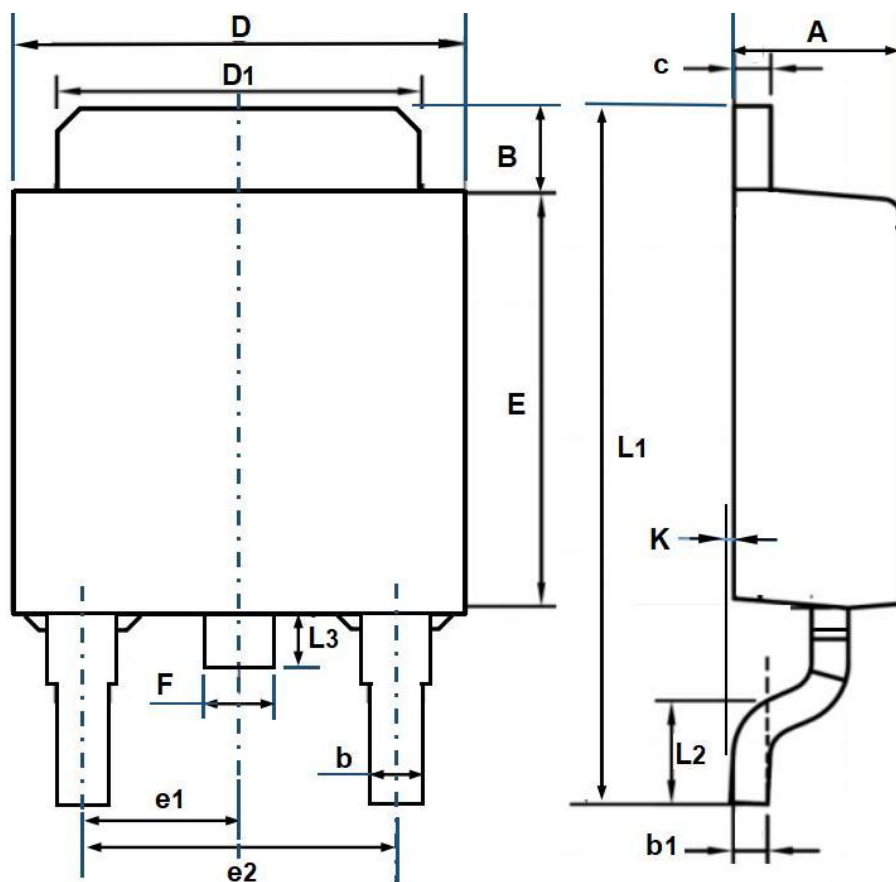
Notes:

- * 1. Repetitive rating, pulse width limited by maximum junction temperature.
- * 2. Pulse Test: Pulse width ≤ 300μs, Duty Cycle ≤ 2%

Typical Feature Curve



Package outline drawing(TO-252 Unit: mm)



符号 SYMBOL	最小值 min	最大值 max	符号 SYMBOL	最小值 min	最大值 max
A	2.20	2.40	B	0.85	1.25
b	0.50	0.80	C	0.45	0.70
b1	0.45	0.70	D	6.30	6.70
D1	5.10	5.50	E	5.30	6.20
L1	9.20	10.60	F	0.50	0.90
L2	0.90	1.50	e1	2.25	2.35
L3	0.60	1.10	e2	4.50	4.70
			K	0.00	0.18

Disclaimers:

Reasunos Semiconductor Technology Co.Ltd (Reasunos) reserves the right to make changes without notice in order to improve reliability,function or design and to discontinue any product or service without notice .Customers should obtain the latest relevant information before orders and should verify that such information in current and complete.All products are sold subject to Reasunos's terms and conditions supplied at the time of orderacknowledgement.

Reasunos Semiconductor Technology Co.Ltd warrants performance of its hardware products to the specifications at the time of sale.Testing,reliability and quality control are used to the extene Reasunos deems necessary to support this warrantee. Except where agreed upon by contr- actual agreement,testing of all parameters of each product is not necessarily performed.

Reasunos Semiconductor Technology Co.Ltd does not assume any liability arising from the use of any product or circuit designs described herein.Customers are responsible for their products and applications using Reasunos's components.To minimize risk,customers must provide adequate design and operating safeguards.

Reasunos Semiconductor Technology Co.Ltd does not warrant or convey any license eith- er expressed or implied under its patent rights,nor the rights of others.Reproduction of inform- ation in Reasunos's data sheets or data books is permissible only if reproduction is without modification oralteration.Reproduction of this information with any alteration is an unfair and deceptive business practice. Reasunos Semiconductor Technology Co.Ltd is not responsi- ble or liable for such altered documentation.

Resale of Reasunos's products with statements different from or beyond the parameters stated by Reasunos Semiconductor Technology Co.Ltd for that product or service voids all exp- ress or implied warranties for the associated Reasunos's product or service and is unfair and deceptive business practice. Reasunos Semiconductor Technology Co.Ltd is not responsi- ble or liable for such statements.

Life Support Policy:

Reasunos Semiconductor Technology Co.Ltd's Products are not authorized for use as cri- tical components in life support devices or systems without the expressed written approval of Reasunos Semiconductor Technology Co.Ltd.

As used herein:

1. Life support devices or systems are devices or systems which: a.are intended for surgical implant into the human body, b.support or sustain life,c.whose failuer to when properly used in accordance with instructions for used provided in the laeling,can be reasonably expected to result in significant injury to the user.

2.A critical component is any component of a life support device or system whose failure to system whose failure to perform can be reasonably expected to cause the failure of the life support device or system,or to affect its safety or effectiveness.